

N-Channel 100 V (D-S) MOSFET

PRODUCT SUMMARY

V_{DS} (V)	$R_{DS(on)}$ (m Ω) (Typ.)	I_D (A) ^a	Q_g (Typ.)
100	208 at $V_{GS} = 10$ V	4	9 nC
	225 at $V_{GS} = 4.5$ V		

FEATURES

- DT-Trench Power MOSFET
- 100 % R_g and UIS Tested
- AEC-Q101 Qualified for Automotive Applications
- ESD Protected

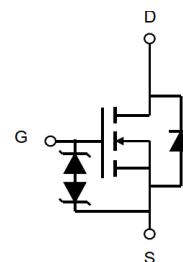
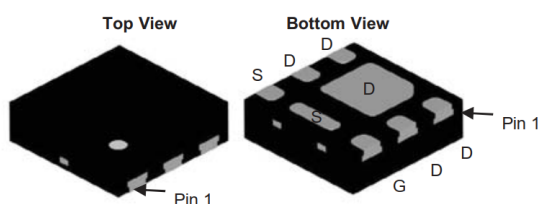
APPLICATIONS

- Switching circuits
- High-speed line driver
- Battery protection applications



RoHS
COMPLIANT

DFN2X2-6L Pin Configuration



ABSOLUTE MAXIMUM RATINGS ($T_A = 25$ °C, unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V_{DS}	100	V
Gate-Source Voltage	V_{GS}	± 20	
Continuous Drain Current ($T_J = 175$ °C)	I_D	4	A
		2.9	
Pulsed Drain Current	I_{DM}	16	
Single-Pulse Avalanche Energy	E_{AS}	8.8	mJ
Maximum Power Dissipation	P_D	16	W
		8	
		2.3 ^{b,c}	
		1.15 ^{b,c}	
Operating Junction and Storage Temperature Range	T_J, T_{stg}	- 55 to 175	°C

THERMAL RESISTANCE RATINGS

Parameter	Symbol	Typical	Maximum	Unit
Maximum Junction-to-Ambient ^{b,d}	R_{thJA}	-	65	°C/W
Maximum Junction-to-Case	R_{thJC}	-	9.8	

Notes:

a. Based on $T_C = 25$ °C.

b. Surface mounted on 1" x 1" FR4 board.

c. $t = 10$ s.

d. Maximum under steady state conditions is 166 °C/W.

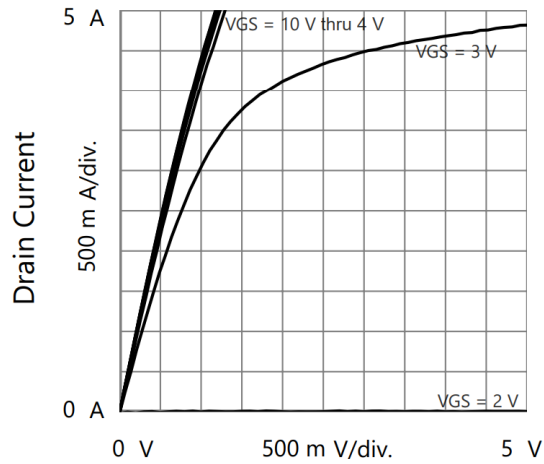
SPECIFICATIONS (T _J = 25 °C, unless otherwise noted)						
Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
Static						
Drain-Source Breakdown Voltage	V _{DS}	V _{GS} = 0, I _D = 250 μA	100			V
Gate-Source Threshold Voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D = 250 μA	1		3	V
Gate-Source Leakage	I _{GSS}	V _{DS} = 0 V, V _{GS} = ± 20 V			± 100	nA
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = 100 V, V _{GS} = 0 V			1	μA
		V _{DS} = 80 V, V _{GS} = 0 V, T _J = 55 °C			10	
On-State Drain Current ^a	I _{D(on)}	V _{DS} ≥ 5 V, V _{GS} = 4.5 V	4.2			A
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = 10 V, I _D = 1.5 A		208	250	mΩ
		V _{GS} = 4.5 V, I _D = 1.5 A		225	310	
Forward Transconductance ^a	g _{fs}	V _{DS} = 10 V, I _D = 1.5 A		5.5		S
Dynamic ^b						
Input Capacitance	C _{iss}	V _{DS} = 50 V, V _{GS} = 0 V, f = 1 MHz		350		pF
Output Capacitance	C _{oss}			15		
Reverse Transfer Capacitance	C _{rss}			9.5		
Total Gate Charge	Q _g	V _{DS} = 50 V, V _{GS} = 10 V, I _D = 1.5 A		9		nC
Gate-Source Charge	Q _{gs}			0.75		
Gate-Drain Charge	Q _{gd}			2		
Gate Resistance	R _g	f = 1 MHz		3		Ω
Turn-On Delay Time	t _{d(on)}	V _{DD} = 50 V, I _D = 1.5 A, V _{GEN} = 10 V, R _g = 1 Ω		9		ns
Rise Time	t _r			13		
Turn-Off DelayTime	t _{d(off)}			12		
Fall Time	t _f			8		
Drain-Source Body Diode Characteristics						
Continous Source-Drain Diode Current	I _S	T _C = 25 °C			4	A
Pulse Diode Forward Current (100 μs)	I _{SM}				16	
Body Diode Voltage	V _{SD}	I _S = 1 A			1.2	V
Body Diode Reverse Recovery Time	t _{rr}	I _F = 1.5 A, dI/dt = 100 A/μs, T _J = 25 °C		28		ns
Body Diode Reverse Recovery Charge	Q _{rr}			16		nC
Reverse Recovery Fall Time	t _a			18		ns
Reverse Recovery Rise Time	t _b			20		

Notes:

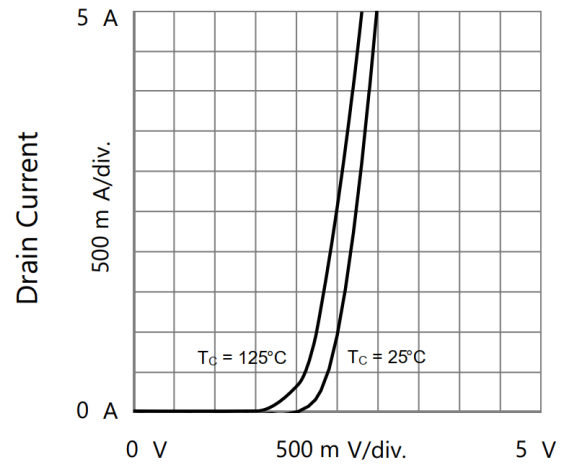
- a. Pulse test; pulse width $\leq 300\text{ }\mu\text{s}$, duty cycle $\leq 2\%$.
 b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

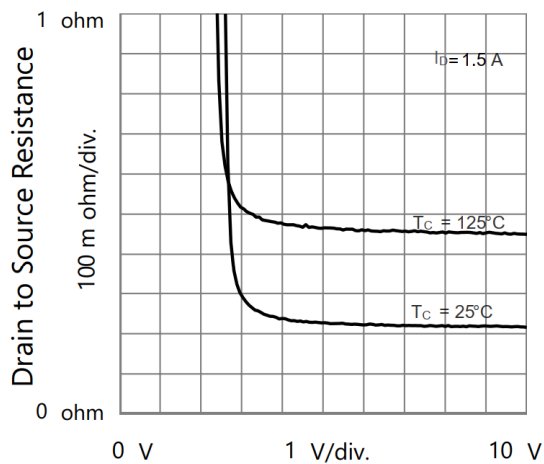
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



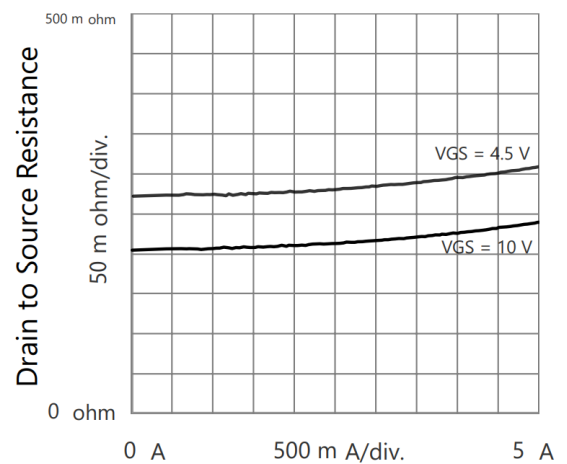
Drain to Source Voltage
Output Characteristics



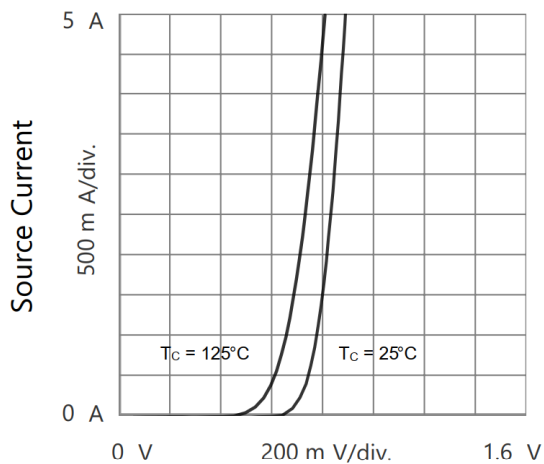
Gate to Source Voltage
Transfer Characteristics



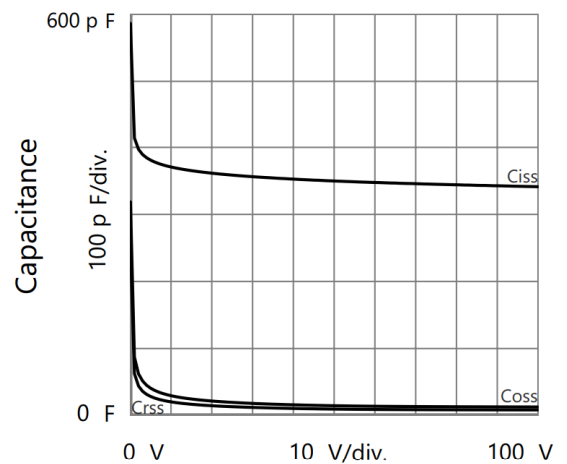
Gate to Source Voltage
Drain to Source Resistance vs. Gate to Source Voltage



Drain Current
Drain to Source Resistance vs. Drain Current

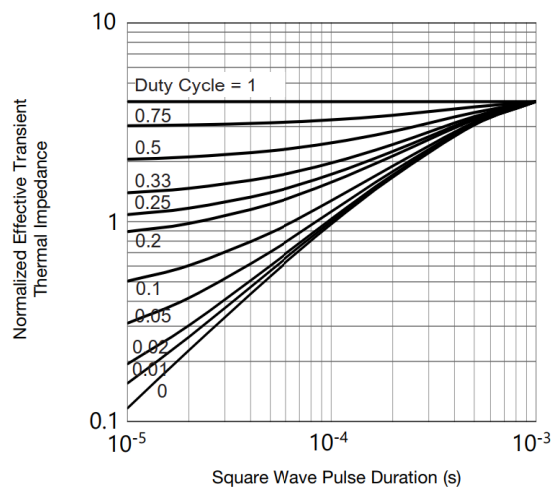
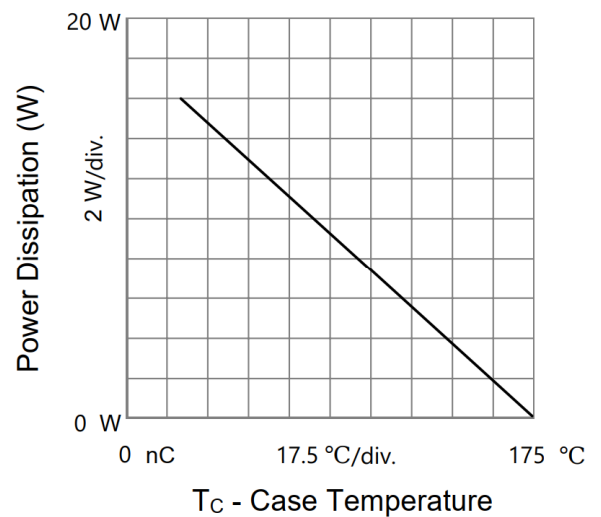
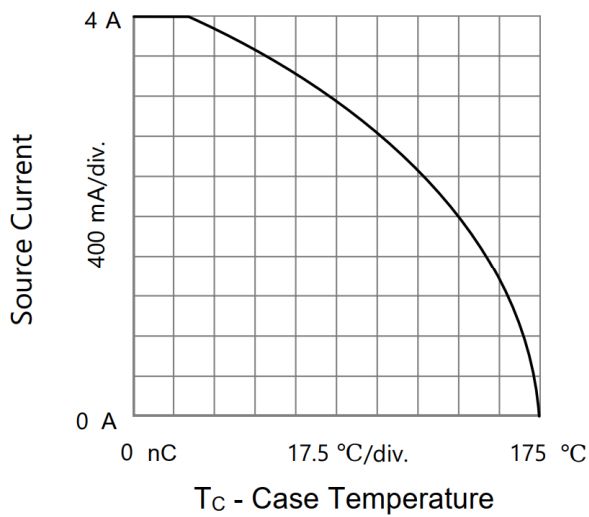
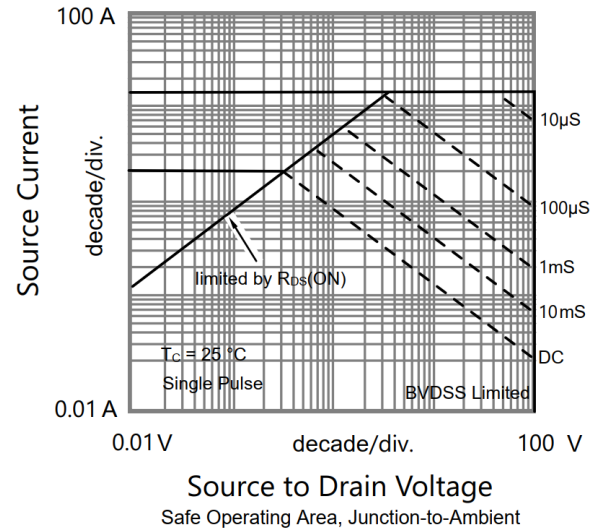
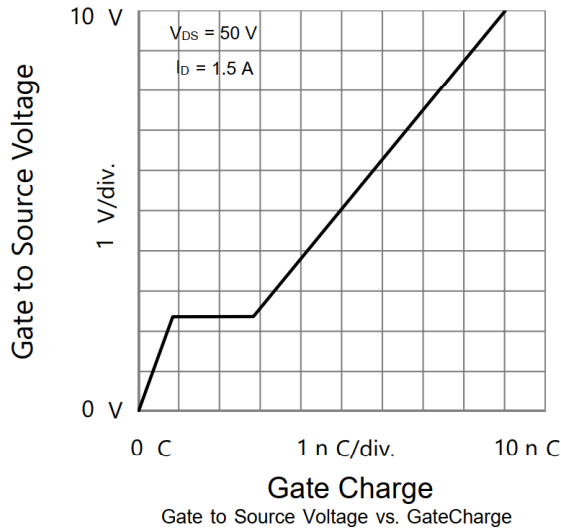


Source to Drain Voltage
Body Diode Forward Characteristics



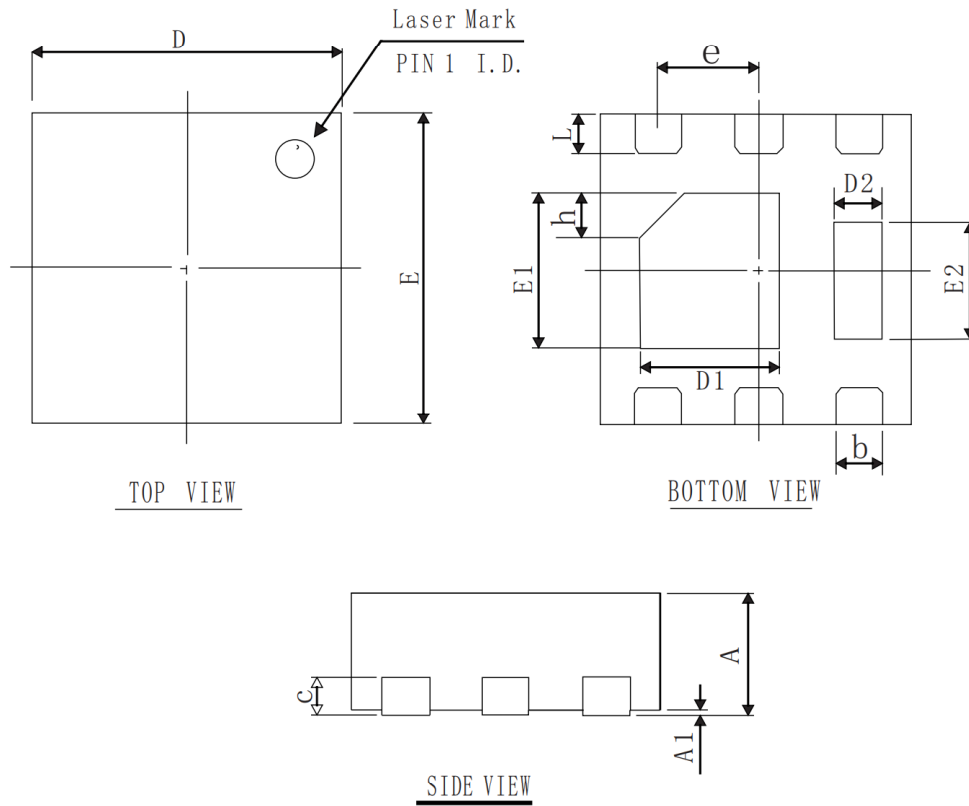
Drain to Source Voltage
Capacitances

TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Case

DFN 2X2 PACKAGE OUTLINE



COMMON DIMENSIONS
(UNITS OF MEASURE=mm)

SYMBOL	MIN	NOM	MAX
A	0.60	0.75	0.90
A1	0.00	0.02	0.10
b	0.15	0.25	0.40
D	1.80	2.00	2.25
E	1.80	2.00	2.25
D1	0.70	0.90	1.10
E1	0.75	1.00	1.20
D2	0.15	0.30	0.45
E2	0.45	0.75	0.95
L	0.15	0.25	0.40
h	0.15	0.25	0.40
c	0.203 REF		
e	0.65 BSC		

Other thickness dimensions are as follows

A	0.50	0.55	0.60
A	0.40	0.45	0.50

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